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Electrochemical nucleation and growth model of MoS₂ for hydrogen evolution reaction

Venumbaka Maneesh Reddy¹ , Marepally Bhanu Chandra² , Saravanan Gengan^{3*} and Selvakumar Duraisamy^{1*}

Abstract

The electrochemical nucleation of MoS₂ from a mixture of sodium molybdate dihydrate (Na₂MoO₄·2H₂O) and sodium sulphide (Na₂S·xH₂O) aqueous solution on Cu substrate has been investigated. The nucleation and formation of molybdenum sulphide were investigated employing cyclic voltammetry and chronoamperometry studies. The experimental *i*-*t* curves observed at various overpotentials were compared to theoretical curves derived for the two limiting situations of the 3D instantaneous/progressive nucleation and growth model, as reported by Scharifker and Hills. The outcome of electrodeposition potential on nucleation rate (*A*) and nucleation density (*N*) was calculated from the current–time transients and SEM morphology obtained at – 1.1 V (5.75×10^{14} and 1.86×10^{15}) was compared with – 0.9 V, – 1.0 V, and – 1.2 V, respectively. The investigation of the initial stages of the transient current–time relationships developed for MoS₂ electrodeposition specified that film formation occurred progressively initially and instantaneous nucleation during the course of time. A HPMoS₂ with an average size of 5–65 nm was obtained at –1.1 V and exhibited superior performance towards the hydrogen evolution reaction compared to samples obtained at – 0.9 V, – 1.0 V, and – 1.2 V.

Introduction

Molybdenum disulphide (MoS₂), a member of the layered transition metal dichalcogenides (TMDCs), has emerged as a promising material for various electronic and optoelectronic applications due to its exceptional physical and chemical properties. TMDCs like MoS₂ have a unique structure, composed of layers of molybdenum (Mo) atoms sandwiched between sulphur (S) atoms, forming a stable S-Mo-S coordination within the

crystal lattice. This layered structure allows for intriguing electrical, mechanical, and chemical characteristics, such as a tuneable band gap, making MoS₂ suitable for a range of semiconductor applications including transistors, photodetectors, and flexible electronics (Mak et al. 2010; Splendiani et al. 2010; Radisavljevic et al. 2011). One of the key advantages of MoS₂ is its abundance and low-cost production, which, combined with its adjustable band gap, enables the development of highly efficient switchable transistors. The band gap of MoS₂ can be modulated based on the number of layers, ranging from an indirect band gap (~1.2 eV) in bulk form to a direct band gap (~1.8 eV) in monolayers. This transition from bulk to monolayer introduces unique optical and electronic properties, which are significantly different from those observed in bulk materials. Such properties have positioned MoS₂ as a leading candidate for next-generation optoelectronic devices, including photodetectors, solar cells, and light-emitting diodes (Lembke and Kis 2012; Yin et al. 2012; Shi et al. 2012). In addition to its

*Correspondence:

Saravanan Gengan
saravanan3che@gmail.com
Selvakumar Duraisamy
selvakumar@psgitech.ac.in

¹ Department of ECE, PSG Institute of Technology and Applied Research, Coimbatore 641062, India

² Chaitanya Bharati Institute of Technology, Hyderabad, Telangana 500075, India

³ Department of Chemistry, Saveetha School of Engineering, Saveetha Institute of Medical and Technical Sciences, Saveetha University, Chennai, Tamil Nadu 602105, India



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electronic applications, MoS₂ exhibits excellent catalytic properties, particularly in photocatalytic and electrocatalytic reactions. The presence of unsaturated molybdenum and sulphur atoms at the edges of the material's crystal lattice creates active sites that facilitate hydrogen production through water splitting. These active sites, resulting from the S-Mo-S coordination, enhance the material's catalytic efficiency, making MoS₂ an attractive material for hydrogen evolution reactions (HER). Its high surface area and catalytic activity, combined with its stability in aqueous environments, further emphasize its potential in renewable energy technologies (Voiry et al. 2016; Yu et al. 2014; Novoselov et al. 2005).

To exploit the properties of MoS₂ for various applications, several fabrication methods have been developed. Top-down techniques, such as micromechanical exfoliation, intercalation-assisted exfoliation, and liquid-phase exfoliation, are widely used to isolate monolayers or few-layer MoS₂ from bulk crystals. These methods, while effective in producing high-quality monolayers, face limitations in terms of scalability and cost for industrial-scale production. Alternatively, bottom-up approaches like physical vapour deposition (PVD), chemical vapour deposition (CVD), and atomic layer deposition (ALD) provide better control over the growth and thickness of MoS₂ films, but these methods can be expensive and challenging to implement on a large scale (Zeng et al. 2017; Li et al. 2014; Yu et al. 2013). Electrochemical deposition (or electrodeposition) offers a cost-effective and scalable alternative for producing MoS₂ thin films and nanoparticles under ambient conditions. This method allows for precise control over critical deposition parameters such as film thickness, particle size, and morphology, making it suitable for large-scale manufacturing. Additionally, electrodeposition occurs under room temperature and pressure conditions, eliminating the need for complex equipment or toxic chemical reducing agents, further enhancing its industrial viability. Recent studies have successfully demonstrated the electrodeposition of MoS₂ onto various substrates, providing insights into the material's nucleation and growth mechanisms (Kong et al. 2014; Alinejadian et al. 2022; Zhou et al. 2013). Despite these advancements, the nucleation and growth dynamics of MoS₂ during electrodeposition remain relatively unexplored. Understanding these mechanisms is crucial for optimizing the electrodeposition process to achieve desired material properties. This study investigates the electrodeposition of MoS₂ at different overpotentials ranging from -0.9 to -1.2 V, using sodium molybdate dihydrate and sodium sulphide as precursors in a potentiostatic, charge-controlled deposition process. By comparing theoretical nucleation models with experimental observations, this research aims

to elucidate the electrochemical behaviour of MoS₂ during deposition. Scanning electron microscopy (SEM) is employed to characterize the morphology of the deposited MoS₂ films, providing insights into how deposition conditions influence the material's structure and properties. This investigation highlights the potential of electrodeposition as a scalable and cost-effective method for fabricating MoS₂ with tunable properties. By operating under room temperature and pressure, and without the need for hazardous chemicals, this technique offers a promising route for the sustainable production of MoS₂ for various industrial applications (Tan and Zhang 2015; Du et al. 2014; Singh et al. 2023; Aslan et al. 2021).

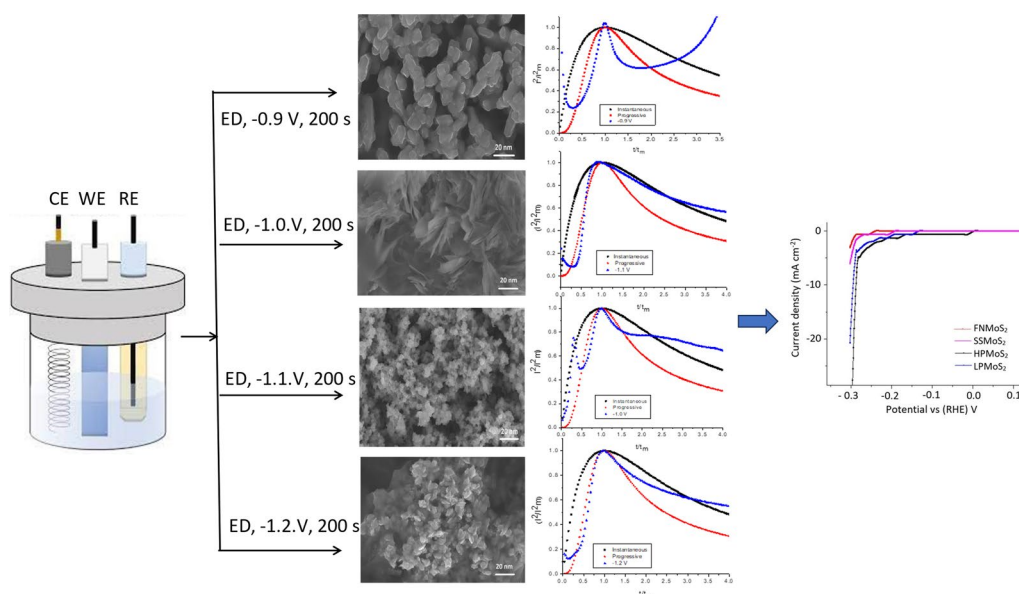
Experimental

Electrochemical preparation of MoS₂ nanostructures on Cu substrate

To investigate the electrochemical phase formation of MoS₂ nanostructures on a Cu substrate, we prepared an electrolyte mixture consisting of 1 M Na₂MoO₄·2H₂O and 0.1 M Na₂S·xH₂O dissolved in 20 ml of Milli-Q water. This mixture was magnetically stirred for 30 min and maintained at 65–70 °C. Following that, the electrodeposition of MoS₂ took place within a three-electrode cell arrangement, with Cu foils serving as the working electrode (WE), Pt mesh electrode as the counter electrode (CE), and a saturated KCl–Ag/AgCl reference electrode (RE). Constant applied (CA) curves were employed for electrodeposition potentials of -0.9 V, -1.0 V, -1.1 V, and -1.2 V, respectively, for a duration of 200 s, as depicted in Scheme 1. The resulting samples were designated as FNMoS₂, SSMoS₂, HPMoS₂, and LPMoS₂, corresponding to the applied potentials. Following electrodeposition, the Cu electrodes with MoS₂ were cleaned using deionized (DD) water to remove any residual electrolyte. To improve adhesion, a drop of a 1:1 mixture of Nafion and ethanol was spread onto the deposited MoS₂, and the electrodes were then allowed to dry overnight at room temperature.

Electrochemical characterization and surface morphology studies

Electrochemical analysis was conducted using a Princeton Applied Research Model PARSTAT 2273 potentiostat–galvanostat, which was controlled by Power Suite software. The experiments utilized a conventional three-electrode electrochemical cell setup. The working electrode consisted of a platinum wire with a surface area of 0.15 cm². These investigations involved potential step cyclic voltammetry, a technique where a series of potential steps are applied to the working electrode to measure resulting currents. This methodology provides valuable insights into the electrochemical behaviour of the system



Scheme 1 Schematic illustration of the electrochemical phase formation of MoS_2 at -0.9 V, -1.0 V, -1.1 V, and -1.2 V, respectively, corresponding SEM images and its dimensionless time vs. dimensionless current instantaneous and progressive nucleation model in mixture ($\text{Na}_2\text{MoO}_4 \cdot 2\text{H}_2\text{O}$ and $\text{Na}_2\text{S} \cdot x\text{H}_2\text{O}$) electrolyte solution

under study, including redox reaction kinetics, surface adsorption processes, and the formation of reaction intermediates. A saturated Ag/AgCl electrode equipped with a Luggin capillary served as the reference electrode, while a platinum sheet acted as the counter electrode. Throughout the experiments, all potentials were applied at values of -0.9 V, -1.0 V, -1.1 V, and -1.2 V, respectively. These potentials were maintained for a duration of 200 s in a solution containing $\text{Na}_2\text{MoO}_4 \cdot 2\text{H}_2\text{O}$ and $\text{Na}_2\text{S} \cdot x\text{H}_2\text{O}$.

Results and discussion

Cyclic voltammetry investigation of formation of MoS_2

In our experiments, tetra thiomolybdate was formed by simply mixing Na_2MoO_4 and Na_2S in Milli-Q water to investigate the formation of MoS_2 through cyclic voltammetry (CV). The CV results revealed a distinct pattern of MoS_3 formation and dissolution, as depicted in Fig. 1. Specifically, MoS_3 film formation was observed through the oxidation of $[\text{MoS}_4]^{2-}$ ions at -0.625 V, followed by its dissolution upon reduction at $+0.3$ V. This observation is consistent with previous literature reports (Shi et al. 2015), suggesting that MoS_3 is generated via the following processes: process (1) oxidation: $[\text{MoS}_4]^{2-} \rightarrow \text{MoS}_3 + \text{S}^{2-}$ —(1), reduction: $\text{MoS}_3 \rightarrow \text{MoS}_4^{2-}$ —(2) however, it is important to note that the reduction of MoS_3 to form MoS_4^{2-} is also possible, potentially due to the reverse reaction of Eq. 1. It is crucial to recognize that both equations are not entirely

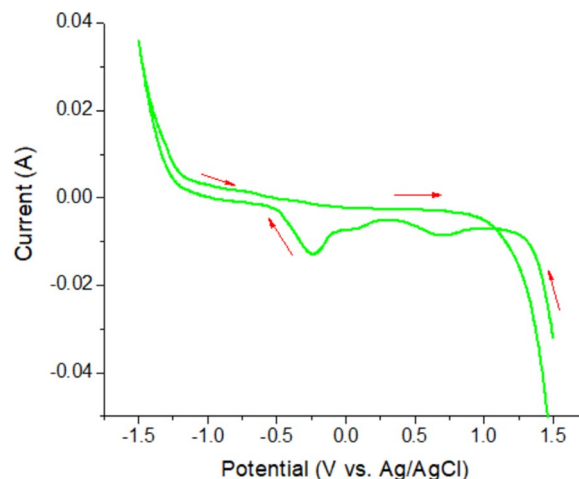
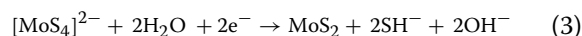
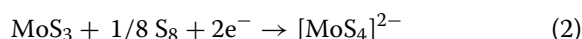


Fig. 1 CV curve recorded in the solution of $\text{Na}_2\text{MoO}_4 \cdot 2\text{H}_2\text{O}$ and $\text{Na}_2\text{S} \cdot \text{XH}_2\text{O}$ in 20 ml of Milli-Q water over the range of -1.5 to $+1.5$ V at scan rate of 5 mV/s

reversible, implying that the comparative rates of electrodeposition and dissolution can be influenced by different electrodeposition parameters. Furthermore, during the negative-going scan at -0.25 V, a reductive deposition is observed. This process can be attributed to the following reaction, consistent with previously reported literature: reductive deposition: Formation of MoS_2 possibly combined through MoS_3 in the film. Moreover, it is worth considering that OH^- and hydrosulphide may mix with

molybdenum during these processes, and these negative groups could potentially undergo additional transformations into numerous O^{2-} and S^{2-} species. For instance, the cyclic voltammetry study reveals a dynamic process of MoS_3 formation and its subsequent dissolution, as well as the possible formation of amorphous MoS_2 . These observations underscore the complexity of the electrochemical nature of MoS_2 and the importance of controlling deposition conditions to tailor the properties of the resulting material.



Electrochemical study of MoS_2 deposition by the chronoamperometric method

To investigate the specific reactions involved in nucleation and growth, chronoamperometric analysis (CA) was employed. CA curves were examined over a potential range from -0.9 to -1.2 V. Figure 2 displays typical fluctuations in current density. Figure 2 shows that the current quickly rises to its maximum value (i_{max} at t_{max}) before gradually declining over time. The abrupt increase in current in the cathodic direction can be attributed to either an augmentation in the number of nuclei or the emergence of a new phase. During the development of the deposit, nuclei generate diffusion zones around themselves. These zones impede hemispherical mass

transfer and facilitate linear mass transfer, resulting in a predominantly flat surface. As the current diminishes due to linear diffusion control, as elucidated by the Cottrell equation, the thickness of the diffusion layer increases (Saravanan and Mohan 2016).

3D instantaneous/progressive nucleation and growth model

Analysing the generated CA curves using equations from the Scharifker–Hills (SH) model can provide insight into the process of nucleation and crystal development, allowing for comparison with acquired data (Cottrell 1903; Scharifker and Hills 1983). According to the proposed model, nucleation processes are categorized into two types: instantaneous and progressive. The instantaneous type entails nucleus development occurring immediately upon the application of the deposition potential. In contrast, progressive nucleation involves the continual proliferation of nuclei during the electrochemical deposition experiment. These two assumptions for instantaneous and gradual nucleation can be expressed as Eqs. (4) and (5).

$$i^2/i_m^2 = 1.9542/(t/t_m) \{1 - \exp[-1.2564(t/t_m)]\}^2 \quad (4)$$

$$i^2/i_m^2 = 1.2254/(t/t_m) \left\{1 - \exp\left[-2.3367(t/t_m)^2\right]\right\}^2 \quad (5)$$

The mathematical study of the nucleation model in the electrolyte solution at different potentials was performed using SH equations (Gunawardena et al. 1982). However, it was discovered that the resultant currents at constant potentials are not always constant, since they are impacted by numerous factors: (1) The nucleation and growth mechanisms of MoS_2 are time and overpotential dependent. (2) The existence of faulty patches and the electrode's surface roughness can help define the usual nucleation and growth mechanisms. These features can make it challenging to explain the deposition behaviour of 3D tiny nodular grains, small sheetlike nanosheets, highly porous, and less porous MoS_2 nanoparticles. Figure 3A–E shows the non-dimensional i^2/i_m^2 vs. t/t_m curves generated from the CA data for MoS_2 deposition, which reflect the theoretically fitted instantaneous and progressive data of nucleation. At the beginning of current growth, a portion of the non-dimensional graph revealed progressive nucleation at -0.9 V, -1.0 V, and -1.2 V, while a mixed type of instantaneous–progressive nucleation was seen at -1.1 V, respectively. Similarly, at the peak of current growth, the non-dimensional plot revealed progressive (-0.9 V), progressive–instantaneous (-1.0 V), instantaneous (-1.1 V), and progressive–instantaneous processes (-1.2 V), corresponding to

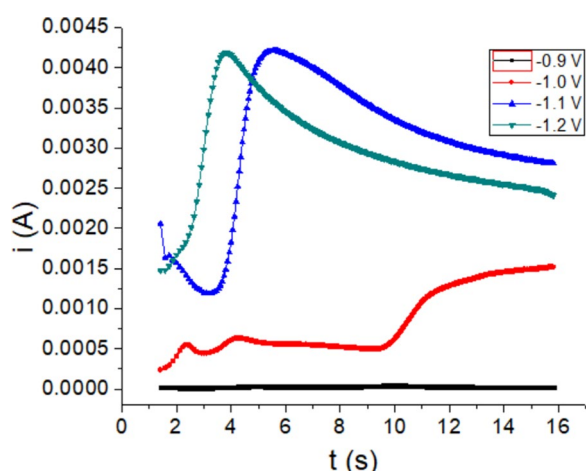


Fig. 2 CA of $FNMoS_2/Cu$, $SSMoS_2/Cu$, $HPMoS_2/Cu$, and $LPMoS_2/Cu$ electrochemical phase formation at -0.9 V, -1.0 V, -1.1 V, and -1.2 V for 200 s, respectively

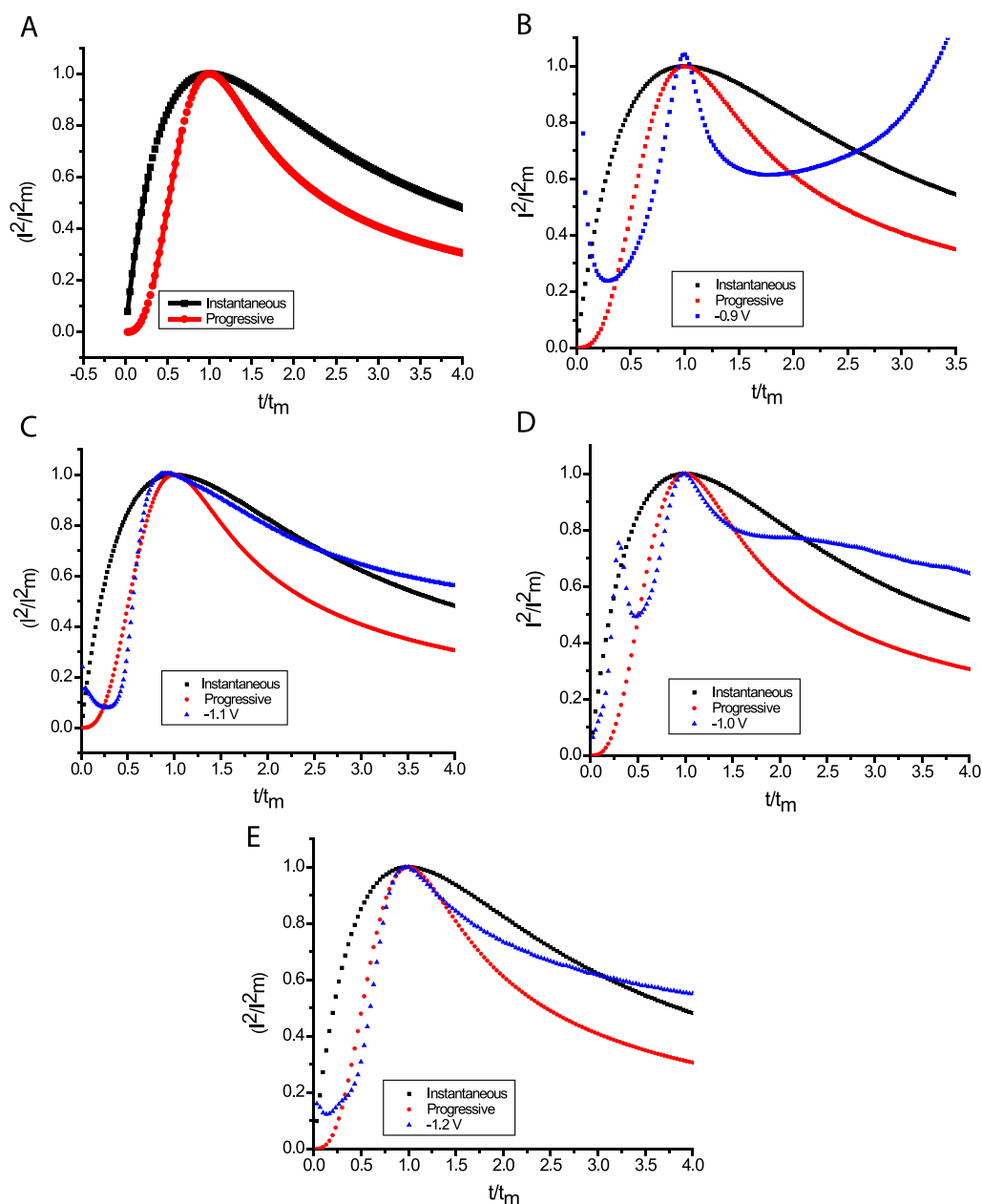


Fig. 3 **A** Theoretical 3D dimensionless time vs. dimensionless current instantaneous and progressive nucleation. **B–E** Comparison of 3D dimensionless time vs. dimensionless current (Eq. (1) and (2)) in $\text{Na}_2\text{MoO}_4 \cdot 2\text{H}_2\text{O}$ and $\text{Na}_2\text{S} \cdot \text{XH}_2\text{O}$ electrolyte solution and fitted experimental data obtained **B** at -0.9 V **C** at -1.0 V , **D** at -1.1 V , and **E** at -1.2 V vs. the saturated Ag/AgCl electrode based on the Scharifker and Hills (S–H) nucleation model

the SH model. Both the current–time rise and the highest section of the CA data from -0.9 to -1.2 V showed a 3D progressive followed by an instantaneous–progressive pattern. The findings given here provide compelling experimental data, corroborated by SEM morphology acquired under the aforementioned electrodeposition settings, demonstrating that MoS_2 is primarily formed

via a 3D progressive followed by immediate nucleation and growth process.

Current–time curves for instantaneous nucleation, diffusion coefficient (D) and island density (N_0)

As per the rate law for instantaneous nucleation ($N(t) = N_0$) and diffusion-limited growth, the current maximum and the time at the current maximum can be

determined by the equation provided below. At the current maximum, the instantaneous nucleation growth model is followed.

$$t_m = 1.2564(\pi DN_0)^{-1}c^{-1/2}(8\pi V_m)^{-1/2} \tag{6}$$

$$i_m = 0.6382zFDc^{5/4}(8\pi V_m)^{1/4}(N_0)^{1/2} \tag{7}$$

The parameters i_m and t_m typically exhibit exponential dependencies on the potential, with i_m increasing and t_m decreasing as the potential shifts to more negative values. The island density N_0 can be obtained by combining Eqs. (6) and (7):

$$N_0 = 0.065(1/8\pi c_0 V_m)^{1/2}(zFc_0/i_m t_m)^2 \tag{8}$$

The MoS₂ nucleation island density N_0 could be estimated using Eq. (5). Table 1 displays the computed N_0 values at -0.9 V, -1.0 V, -1.1 V, and -1.2 V, which are 7.89×10^{10} , 1.02×10^{13} , 1.86×10^{15} , and 3.69×10^{11} , respectively. At -1.1 V, a greater magnitude island density is achieved because progressive and immediate nucleation behaviour is observed at the present growing component. Lower N_0 values at -0.9 V, -1.0 V, and -1.2 V, on the other hand, might be attributed to progressive nucleation in the early stage as well as mixed types of progressive-instantaneous nucleation at the present growing region of the $i-t$ curve, hence reducing island density. This discovery is compatible with the SEM morphology shown in Fig. 4A–D, respectively. Extracting the diffusion coefficient of the deposited species provides additional verification of the growth process. According to the model for instantaneous nucleation, the diffusion coefficient is linked to the current maximum and the time at the maximum, as seen below (Saravanan and Mohan 2020).

$$D = i_m^2 t_m / 0.1629(zFc_0)^2 \tag{9}$$

The given diffusion coefficient $D_0 = 8.5 \times 10^{-5} \text{ cm}^2 \text{ s}^{-1}$ indicates the rate at which ions diffuse in the solution. Since it is relatively high, it suggests that the ions are

moving quite rapidly despite the low concentration of 1 M of Na₂MoO₄·2H₂O.

Current-time curves for progressive nucleation, diffusion coefficient (D) and nucleation rate ($k_n N_0$)

Progressive followed by instantaneous nucleation ($N_{(t)} = k_n N_0$) and diffusion-controlled growth, the current summit and the time at the current maximum are given by Eqs. (10) and (11).

$$i_m = 0.4959zFD^{3/4}C^{9/8}(8\pi V_m)^{1/8}(k_n N_0)^{1/4} \tag{10}$$

$$t_m = 3.318D^{-1/2}(8\pi c V_m)^{-1/4}(k_n N_0)^{-1/2} \tag{11}$$

The potential necessity of a set of deposition current transients is primarily administered by the potential need of the nucleation rate $k_n N_0$. The nucleation rate ($i_{\text{nucl}} = dN_{(t)}/dt = k_n N_0$) could be obtained by merging the equations for i_m and t_m for progressive nucleation.

$$k_n N_0 = 0.2898(8\pi c_0 V_m)^{-1/2}(zFc_0)^2/i_m^2 t_m^3 \tag{12}$$

Hence, the nucleation rates for -0.9 V, -1.0 V, -1.1 V, and -1.2 V potentials were computed using Eq. (9). The degrees of the calculated nucleation rates at -0.9 V, -1.0 V, -1.1 V, and -1.2 V are 1.46×10^{10} , 3.29×10^{12} , 5.75×10^{14} , and 1.47×10^{11} , respectively. For progressive and mixed kinds of instantaneous-progressive nucleation, the diffusion coefficient is derived from Eq. (9) and given as Eq. (13).

$$D = i_m^2 t_m / 0.2598(zFc_0)^2 \tag{13}$$

To determine the process of nucleation, compare the two extreme nucleation current transient data at the early stage and at the current maxima of electrochemical deposition for instantaneous and progressive models, as shown in (14) and (15).

$$I(t) = zFD^{1/2}C/\pi^{1/2}t^{1/2}[1 - \exp(-N\pi kDt)] \tag{14}$$

$$I(t) = zFD^{1/2}C/\pi^{1/2}t^{1/2}\left[1 - \exp\left(-AN_\infty\pi k'Dt^2/2\right)\right] \tag{15}$$

Table 1 Shows the effect of electrodeposition potential on the nucleation model, nucleation (island) density and nucleation rate the computed N_0 values at -0.9 V, -1.0 V, -1.1 V, and -1.2 V, which are 7.89×10^{10} , 1.02×10^{13} , 1.86×10^{15} , and 3.69×10^{11} , respectively

Electrodeposition potential	t_m (s)	i_m (A)	$t_m i_m$	A	N_0	Initial stage Instantaneous (I)/ progressive(P)	Current maximum Instantaneous (I)/ progressive (P)
-0.9	32	4.2×10^{-3}	134.4×10^{-3}	1.46×10^{10}	7.89×10^{10}	P	P
-1.0	18.5	6.38×10^{-4}	118.0×10^{-4}	3.29×10^{12}	1.02×10^{13}	I & P	P & I
-1.1	24.5	3.57×10^{-5}	87.4×10^{-5}	5.75×10^{14}	1.86×10^{15}	P	I
-1.2	15	4.19×10^{-3}	62.8×10^{-3}	1.47×10^{11}	3.69×10^{11}	P	P & I

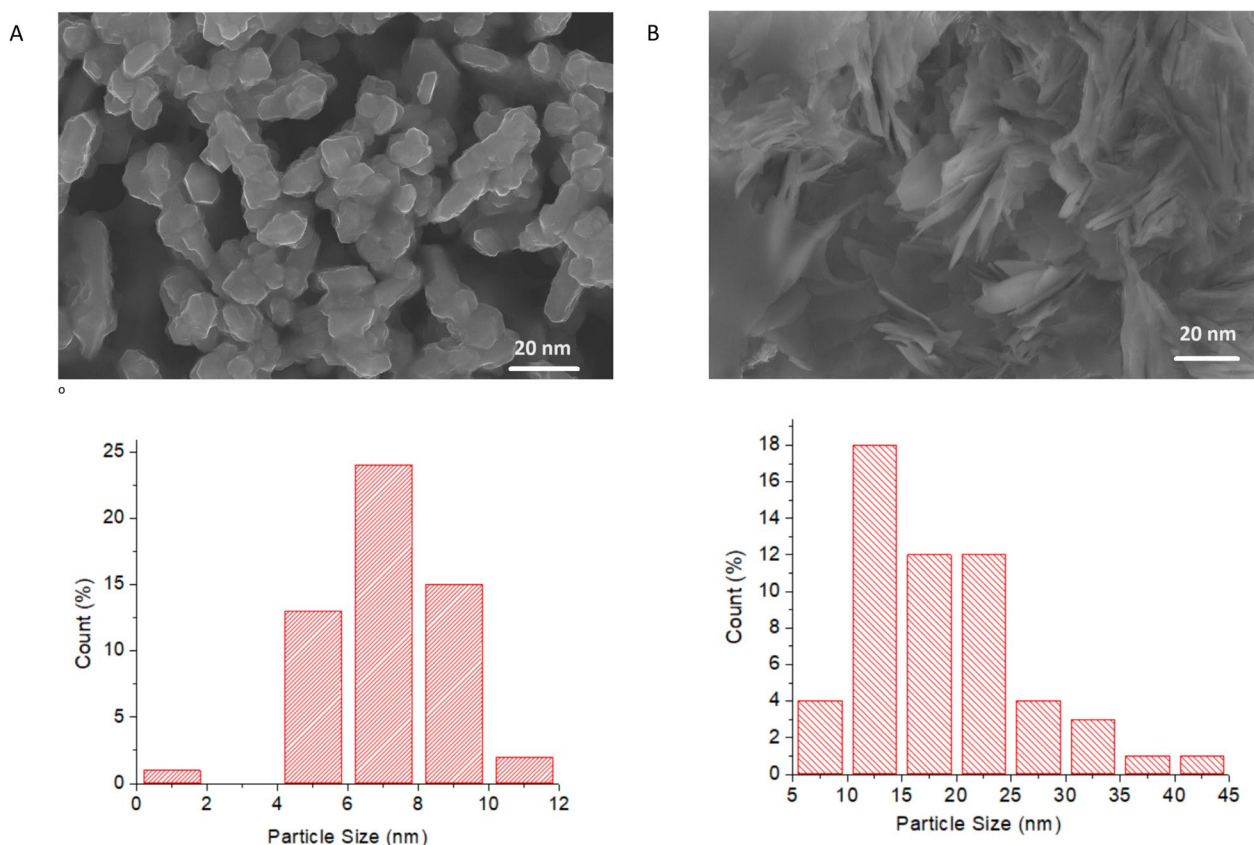


Fig. 4 A–D SEM morphologies of electrodeposited fine nodular FNMoS₂/Cu, small sheet SSMoS₂/Cu, highly porous HPMoS₂/Cu, and low porous LPMoS₂/Cu at -0.9 , -1.0 , -1.1 , and -1.2 V, respectively, corresponding histogram of particle size distribution

Referring to the formulas, $i(t)$ is the current density, t is time, z is the valency of Mo ion, F is Faraday's constant, D is the diffusion coefficient, C is the bulk concentration of Mo ion, and k and k' are arithmetic constants determined by unique experimental conditions. A indicates the steady-state nucleation rate per site, while N_{∞} represents the active site density.

It seems like you are referring to a mathematical derivation involving electrochemical deposition. Equation (4) probably represents the original expression, while Eq. (16) is the simplified form obtained when a certain condition holds, as described by, $N\pi kDt \ll 1$. This condition implies that the product of $1 - \exp(-N\pi kDt) = N\pi kDt$ is much smaller than 1, leading to a simplification of the expression.

$$I(t) = zFD^{3/2}C\pi^{1/2}Nkt^{1/2} \quad (16)$$

And similarly, since $1 - \exp(-AN_{\infty}\pi k'Dt^2/2) = AN_{\infty}\pi k'Dt^2/2$ Eq. (17) becomes

$$I(t) = \frac{1}{2}zFD^{3/2}C\pi^{1/2}AN_{\infty}k't^{3/2} \quad (17)$$

Equations (16) and (17) indicate that the plots of I versus $t^{1/2}$ for instantaneous nucleation and I versus $t^{3/2}$ for progressive nucleation should exhibit linearity, as demonstrated in Fig. 5A and B. Moreover, further expressions can be derived to relate $I_{\max}^2 t_{\max}$ to the diffusion coefficient of electroactive metal ions, as described by the following equations (Wojtalik et al. 2020).

For instantaneous nucleation, $i_{\max}^2 \times t_{\max} = 0.1629 (zFC)2D$, and for progressive nucleation, it is $i_{\max}^2 \times t_{\max} = 0.2598(zFC)2D$. Since the terms on the right-hand side of these equations are independent of applied potential, as per the Scharifker–Hill model, $I_{\max}^2 \times t_{\max}$ must be unaffected by the applied potential. Table 1 provides the values of $I_{\max} t_{\max}$ and $I_{\max}^2 \times t_{\max}$ for various overpotentials (Budevski et al. 1996).

Effect of deposition potential and morphology

The surface morphologies of MoS₂ were analysed using transmission electron microscopy (TEM), as depicted in Fig. 6. The impact of deposition potential on the morphology of FNMoS₂, SSMoS₂, HPMoS₂, and LPMoS₂ was investigated through TEM. The results revealed that the deposition potential primarily influences the density of

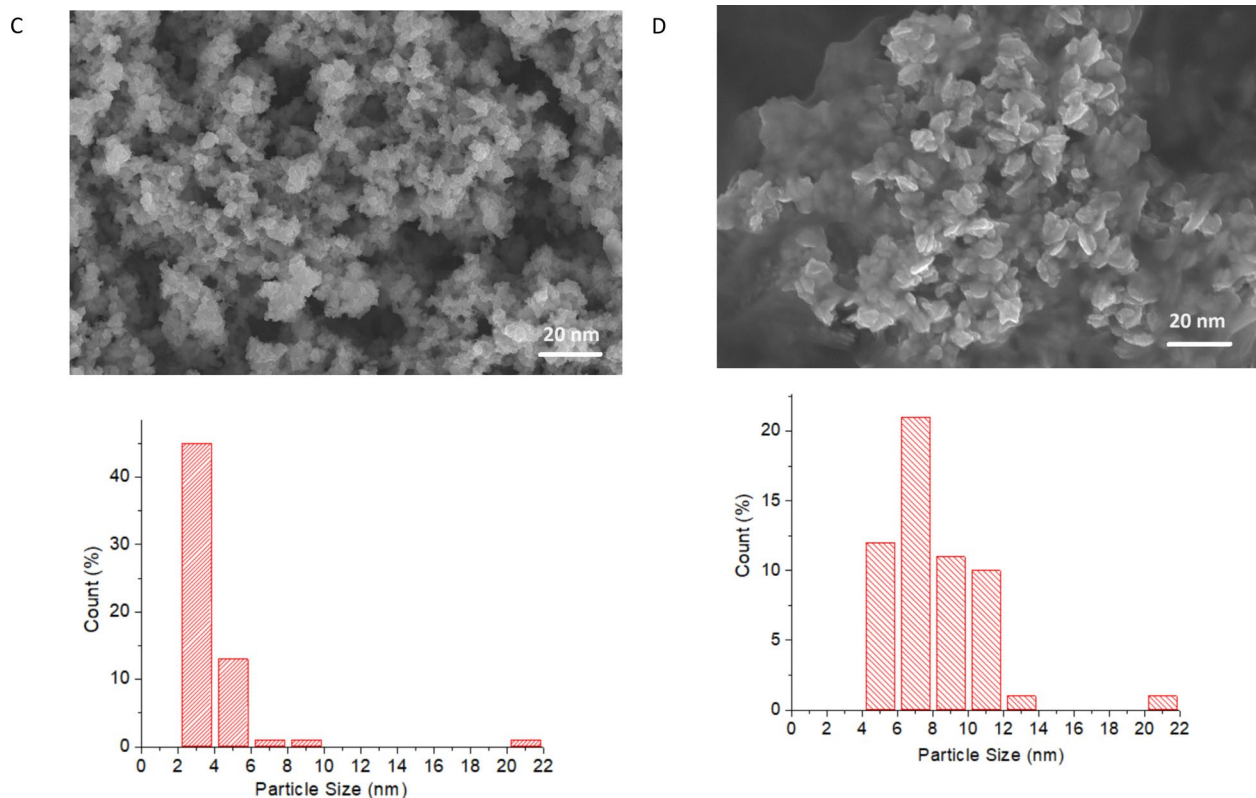


Fig. 4 continued

MoS₂ nuclei within the range of -0.9 V, -1.0 V, -1.1 V, and -1.2 V. Figure 6A–D shows that the fine nodular nuclei were smaller, with small sheetlike morphology and highly porous small nuclei, with nucleation island density N_0 calculated value (Table 1), consistent with TEM images. The measured population density increases with increasing deposition potential from -0.9 to -1.1 V, from 7.89×10^{10} , 1.86×10^{15} and then started to decrease to 3.69×10^{11} . The rise in population density at higher deposition potential can be attributed to the shift from progressive to instantaneous nucleation growth. This transition involves the formation of new nuclei alongside existing ones. Conversely, the decrease observed at higher overpotential may be linked to progressive nucleation occurring in both the initial and current growing parts of the cathodic area. Therefore, the overall total nucleation density increased. The TEM images of FNMoS₂, SSMoS₂, HPMoS₂, and LPMoS₂ also support the calculated nucleation density (N_0) and nucleation rate (A) and the average sizes are $6-8 \pm 1.5$ nm, $10-25 \pm 2$ nm, $2-4 \pm 1.3$ nm and $6-8 \pm 1.5$ nm, respectively.

From the high-resolution transmission electron microscopy (HRTEM) image of the 1 T phase of HPMoS₂, a trigonal lattice with octahedral coordination is displayed, showing an intersheet spacing of 0.634 nm, which may be

attributed to intercalated Na⁺ ions. On the other hand, the samples of FNMoS₂/Cu, SSMoS₂/Cu, and LPMoS₂/Cu exhibit a honeycomb hexagonal lattice, characteristic of the 2H phase. This lattice consists of 3 Mo atoms and 3 overlapped S atoms. This discussion prompts an examination of the interplanar spacing of the (002) plane in relation to electrodeposited HPMoS₂ at -1.1 V, which predominantly forms the 1 T phase with a larger interplanar d-spacing. Other electrodeposited materials, such as FNMoS₂, SSMoS₂, and LPMoS₂, mostly adopt the 2H phase, exhibiting smaller d-spacings than those observed in HPMoS₂. Figure 7 illustrates the evaluation of the hydrogen evolution reaction (HER) process via linear sweep voltammetry (LSV) studies. These studies were performed with a sweep rate of 5 mV s^{-1} , covering a potential range from -0.8 to 0.5 V. Notably, the HPMoS₂/Cu-modified electrode exhibited a significant cathodic current in the small overpotential region, achieving an onset potential of -287 mV at a current density of 10 mA/cm^2 . This result is similar to the performance of Pt/C 20%, to a certain extent. Furthermore, FNMoS₂/Cu, SSMoS₂/Cu, and LPMoS₂/Cu have demonstrated improved HER performance, achieving onset potentials of -305 mV, -327 mV, and -332 mV, respectively. To elaborate, the 1 T phase of the HPMoS₂/Cu electrocatalyst possesses an expanded d-spacing and highly

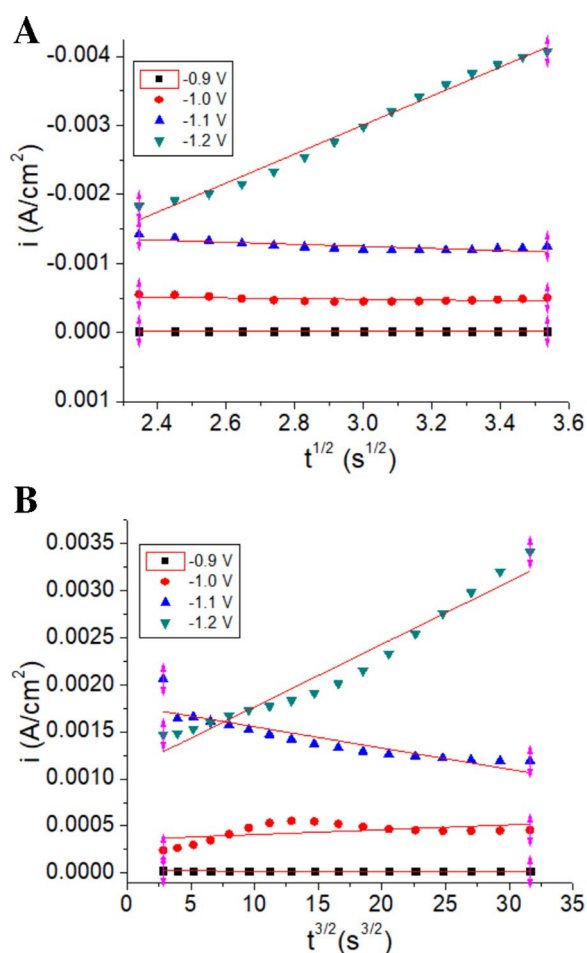
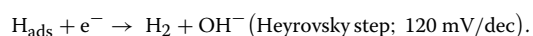
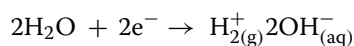


Fig. 5 A Plot of early stage of current transient curves for electrochemical phase formation MoS₂ on Cu 5A in I vs $t^{1/2}$ and B in I vs $t^{3/2}$ which shows curve fitting to experimental data

porous nanostructure, which enhances electron and electrolyte transport, thereby accelerating the electrocatalytic HER process. Tafel plots, which plot log current density against overpotential, provide a quantitative analysis of the electrode kinetics of the HER process. To enhance comprehension of the HER catalytic mechanism in KOH medium, a detailed explanation of the three principal steps that have been proposed and are involved in this process is required.



Several strategies have been developed to enhance the performance and reliability of MoS₂ materials for the hydrogen evolution reaction (HER). One such approach involves: (a) augmenting the quantity of exposed active edge sites, as detailed in the literature (Oskam et al. 1998; Xie et al. 2013); (b) improving the electrical conductivity and diffusion of MoS₂ electrocatalysts, as described in references (Ambrosi et al. 2015a; Lukowski et al. 2014; Zhang et al. 2015); and (c) enhancing catalytic activities of active sites through intercalation, as described in reference (Ambrosi et al. 2015b). It is important to note that MoS₂ can exist in two phases: trigonal prismatic 2H and octahedral 1T. Naturally occurring MoS₂ tends to be semiconducting and thermodynamically favours the 2H phase. However, the 1T metallic phase can be achieved through exfoliating bulk 2H-MoS₂ chemically or electrochemically. The 2H phase of MoS₂ has limitations, including limited active sites and inadequate electron transfer properties which can limit catalytic performance. In order to enhance the catalytic performance of the 2H phase, it can be electrochemically converted into the 1T phase, which has been shown to exhibit advanced catalytic activity compared to the 2H phase is attributed to its active edge and basal planes. The exceptional catalytic properties of the 1T phase of MoS₂ are associated with its high affinity for water, strong electron transport, and ability to interact with various ions. However, to gain a comprehensive understanding of the electrocatalytic nature of 1T-MoS₂, further investigation is needed into its interfacial properties, electrical conductivity, active sites, and the specific type of hydrogen evolution reaction (HER) mechanism it facilitates. The catalytic activity of basal surfaces can be increased through intercalation processes, which create more active sites such as terraces, kinks, steps, and corner atoms via surface engineering. These active sites have the potential to significantly enhance the catalytic activity of the hydrogen evolution reaction (HER). When a sodium ion is intercalated into HPMoS₂ nanosheets, the intersheet d-spacing increases from 0.613 to 0.643 nm. However, it is important to note that only alkali metal ions with appropriate radii can successfully penetrate the interlayer gap distance of HPMoS₂. When discussing the hydrogen adsorption sites in the context of the HER, it is important to clarify that the reactant changes depending on whether the medium

is acidic or basic. In acidic media, the reactant is hydronium (H₃O⁺), while in basic media, the reactant is water (H₂O). During the simple step for the reaction, the H⁻_{ads} species appears to be the primary intermediate on the electrode surface.

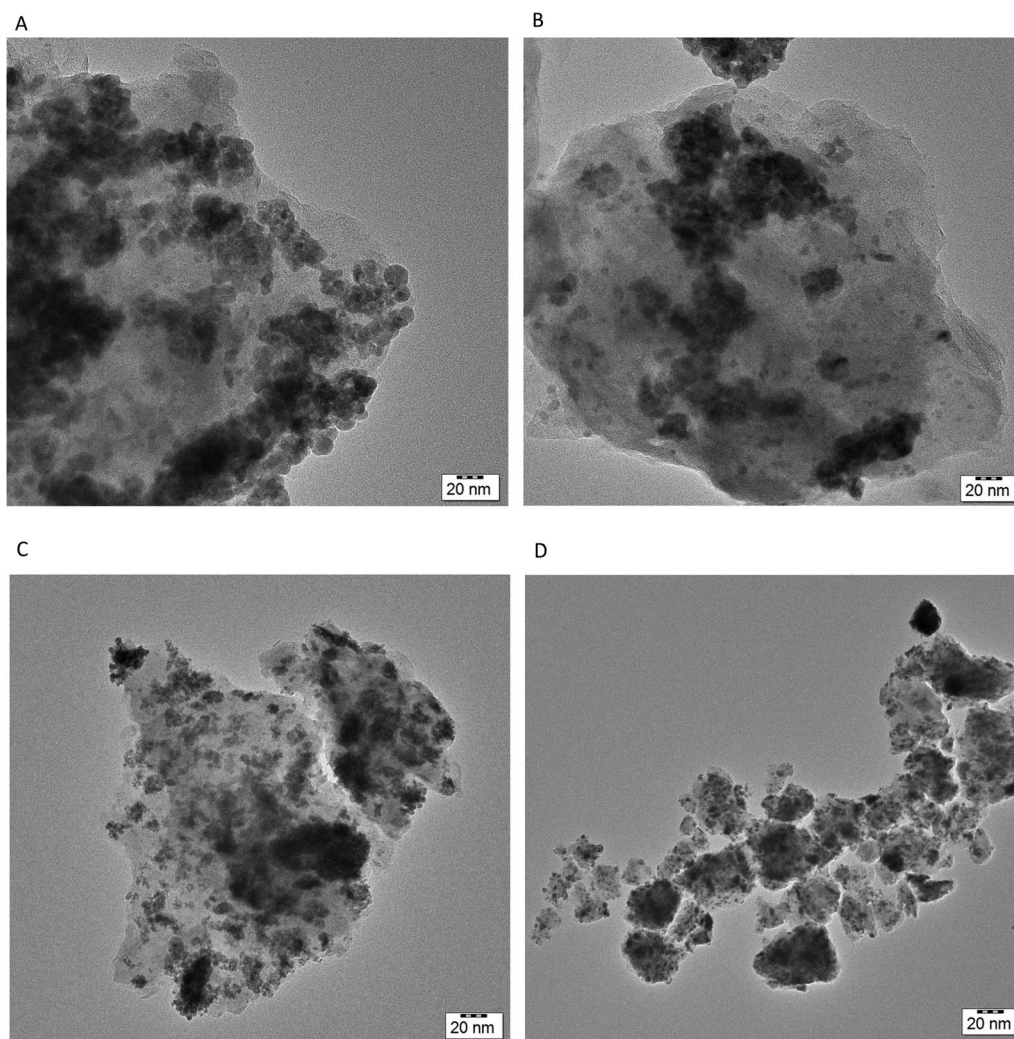


Fig. 6 A–D TEM images of electrodeposited FNMoS₂/Cu, SSMoS₂/Cu, HPMoS₂/Cu, and LPMoS₂/Cu at –0.9, –1.0, –1.1, and –1.2 V, respectively

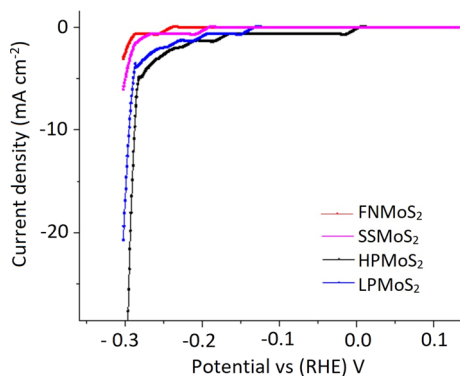


Fig. 7 Representative linear sweep voltammetry (LSV) measurements were taken in 0.5 M KOH with a scan rate of 5 mV s⁻¹ over the potential range of –0.8 to 0.5 V for FNMoS₂/Cu, SSMoS₂/Cu, HPMoS₂/Cu, and LPMoS₂/Cu at –0.9, –1.0, –1.1, and –1.2 V, respectively

As a result, methods such as surface assimilation and sorption of adsorbed hydrogen (H) atoms become viable options. However, there is competition for these methods in both acidic and basic environments, where anions like Cl⁻, ClO₄⁻, and SO₄²⁻ or OH⁻ can impact the complete hydrogen binding energy quanta. Therefore, achieving the optimal hydrogen binding energy is crucial for maintaining a balance between the adsorption and removal of hydrogen intermediates in basic solutions. The first step of the hydrogen evolution reaction (HER) on the basal sheet of 1 T-HPMoS₂ entails the adsorption of a hydrogen atom on the sulphur (S) atom, with a minor barrier of 0.16 eV. This is succeeded by a Heyrovsky step, where the adsorbed hydrogen atom reacts with a proton (H₃O⁺) to generate H₂, passing through a barrier of 0.62 eV. This indicates that HER occurs readily on the basal sheet of 1 T-HPMoS₂ through the Volmer–Tafel mechanism. Previous studies have reported that intercalation of alkali

and alkaline earth ions into the 1 T-MoS₂ intersheet area resulted in a decrease in the overpotential of the HER process.

Conclusions

The combination of electrochemistry with scanning electron microscopy (SEM) proved to be a successful experimental approach for studying the nucleation and growth model of MoS₂ during the initial stages of electrodeposition. Electrochemical techniques served a dual role: (a) facilitating MoS₂ electrodeposition and (b) providing mechanistic interpretation. SEM proved invaluable in linking MoS₂ size distribution with electrochemical observations. Among the parameters explored, it was noted that a transition from progressive nucleation to a mixed instantaneous–progressive nucleation occurred during the initial current growth stage, spanning potentials from -0.9 to -1.2 V. Similarly, during the current growth maximum stage, the non-dimensional plot exhibited a progression from progressive nucleation (-0.9 V) to progressive–instantaneous nucleation (-1.0 V), followed by instantaneous nucleation (-1.1 V), and a mix of progressive–instantaneous mechanism (-1.2 V) according to the Scharifker–Hills (SH) model. Overall, the 3D progressive followed by instantaneous–progressive mechanism was observed both for the increase in current over time and at the maximum part of the chronoamperometric data across the potential range from -0.9 to -1.2 V. The observations presented here provide convincing experimental evidence, supported by SEM morphology, that MoS₂ is predominantly obtained through the 3D progressive followed by instantaneous nucleation and growth mechanism under the mentioned electrodeposition conditions. The MoS₂ nucleation island density (N_0) and nucleation rate (A) values at -0.9 V, -1.0 V, -1.1 V, and -1.2 V are 7.89×10^{10} , 1.02×10^{13} , 1.86×10^{15} , and 3.69×10^{11} , and 1.46×10^{10} , 3.29×10^{12} , 5.75×10^{14} , and 1.47×10^{11} , respectively. A higher magnitude island density is obtained at -1.1 V, attributed to the progressive at initial and instantaneous nucleation behaviour during the current growth phase, which reduces the island density. This observation aligns with the SEM and TEM morphology results. These findings may open up new avenues for developing novel, earth-abundant, low-cost, and highly efficient transition metal dichalcogenide (TMDC)-based electrocatalysts for hydrogen evolution reactions.

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Author contributions

Venumbaka Maneesh Reddy—Conceptualization, Methodology. Marepally Bhanu Chandra—Funding acquisition, Investigation. Saravanan Gengan—Methodology, Writing-original draft, Visualization. Selvakumar Duraisamy—Supervision, editing draft.

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Availability of data and materials

All the data are available in our attachment files like manuscript, figures, and table.

Declarations

Ethics approval and consent to participate

1. All experiments were performed in compliance with relevant laws/guidelines. 2. The experiments followed institutional guidelines. 3. The relevant institutional committee approved the experiments. 4. Informed consent was obtained.

Competing interests

The authors declare no competing financial interest.

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